

2SC4591

Silicon NPN Epitaxial

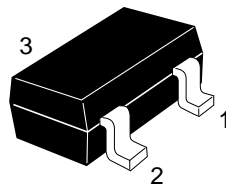
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Application

UHF / VHF wide band amplifier

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector

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Absolute Maximum Ratings (Ta = 25°C)

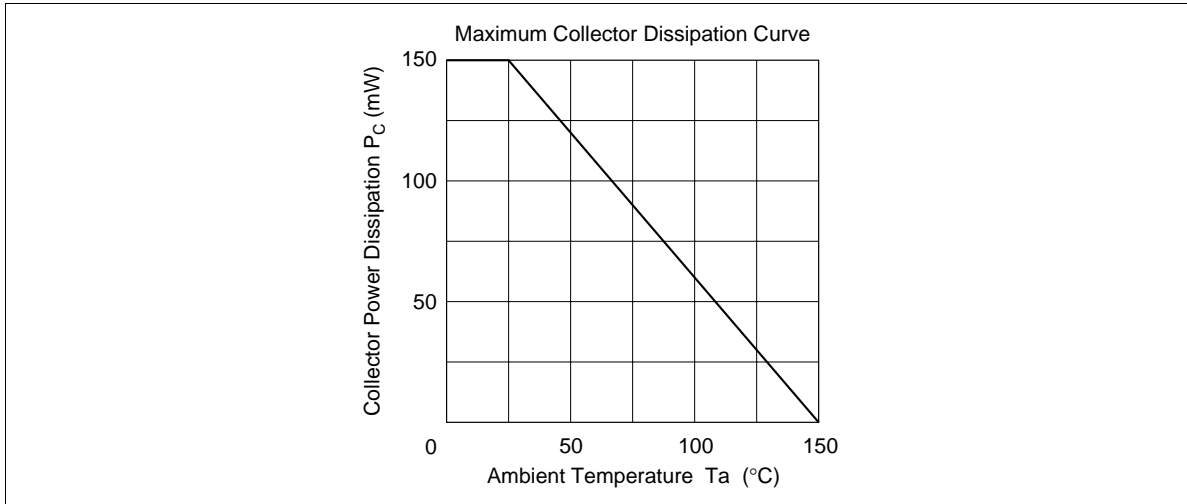
Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	15	V
Collector to emitter voltage	V_{CEO}	9	V
Emitter to base voltage	V_{EBO}	1.5	V
Collector current	I_C	50	mA
Collector power dissipation	P_C	150	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	15	—	—	V	$I_C = 10 \mu A, I_E = 0$
Collector cutoff current	I_{CBO}	—	—	1	μA	$V_{CB} = 12 V, I_E = 0$
	I_{CEO}	—	—	1	mA	$V_{CE} = 9 V, R_{BE} = \infty$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{EB} = 1.5 V, I_C = 0$
DC current transfer ratio	h_{FE}	40	120	250	—	$V_{CE} = 5 V, I_C = 20 mA$
Collector output capacitance	C_{ob}	—	0.8	1.5	pF	$V_{CB} = 5 V, I_E = 0,$ $f = 1MHz$
Gain bandwidth product	f_T	6.5	9.0	—	GHz	$V_{CE} = 5 V, I_C = 20 mA$
Power gain	PG	9.5	12.5	—	dB	$V_{CE} = 5 V, I_C = 20 mA,$ $f = 900 MHz$
Noise figure	NF	—	1.2	2.5	dB	$V_{CE} = 5 V, I_C = 5 mA,$ $f = 900 MHz$

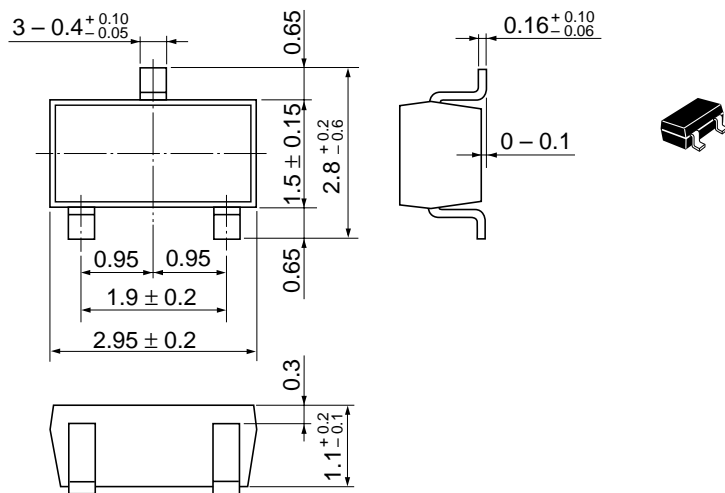
Note: Marking is "XM-".

See characteristic curve of 2SC4592



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Unit: mm



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.011 g

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